

Environment assisted and environment hampered efficiency at maximum power in a molecular photo cell

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The molecular photo cell, i.e., a single molecule donor-acceptor complex, beside being technologically important, is a paradigmatic example of a many-body system operating in strong non-equilibrium. The quantum transport and the photo-voltaic energy conversion efficiency of the photocell, attached to two external leads, are investigated within the open quantum system approach by solving the Lindblad master equation. The interplay of the vibrational degrees of freedom corresponding to the molecules (via the electron-phonon interaction) and the environment (via dephasing) shows its signature in the efficiency at maximum power. We find vibration assisted electron transport in the medium to strong electron-phonon coupling regime when the system does not suffer dephasing. Exposure to dephasing hampers such a vibration assisted electron transport in a specific range of dephasing rate.

I. INTRODUCTION

Molecular junctions, i.e., single molecules or molecular layers placed between metal/semi-conductor electrodes is widely investigated due to it being a platform for studying fundamental aspects of non-equilibrium many body physics at the nano-meter scale, and its possible technological applications^{1–5}. One such potential application (out of many) is the photo-voltaic (PV) cell, where the energy of incident photons is converted into electric current^{6–8}. In PV cells the interplay of the heat current originating from the temperature difference between the photon bath and the system (being at the ambient temperature), and the charge current originating from the bias voltage between the electrodes pushes the system to the strong non-equilibrium regime^{9,10}. The operation of the molecular photo-cell has emerged as a rich theoretical problem, combining both fundamental understanding of quantum transport and relevance to possible applications.^{11–17}

The coupling of electronic degrees of freedom with the internal vibrations of the molecule may play a decisive role in charge transport though the molecular junction^{18–23}. Analogous to the double slit experiment, in an electron only picture different pathways available for electron transfer in the molecular junctions interfere destructively to result in a small output current. Interactions with internal vibrations of molecules, available in the molecular junction, can quench the destructive interference between the electronic pathways thereby opening up more channels for transport, and lead to an enhanced current^{24,25}.

Coupling of electrons to the vibrations serves as an internal source of interruption of the phase coherent transport in molecular junctions. Apart from such a mechanism, phase coherent destructive interference of different electron transport channels can be destroyed

by pure dephasing. This may result in enhanced transport current and efficiency, a phenomenon called “environment assisted quantum transport” (ENAQT)²⁶. The phenomenon of ENAQT has been investigated quite extensively in the field of quantum biology in relation to the performance of photosynthetic systems^{27–31}. Although the role of ENAQT in the performance of photo synthesis is much debated, its occurrence has recently been demonstrated in engineered quantum systems such as qubit, and optical cavity based networks^{32–34}. The conceptual similarity between natural photosynthetic systems and molecular photo-cells naturally raises the question - can the molecular environment (i.e. vibrations) assist the operation of a molecular photo-cell, and under which conditions?

Here we investigate, by analysing the transport efficiency (at maximum power), the possibility of vibration assisted transport and ENAQT when the molecular junctions is used as a PV cell. It is shown that, within our generic model of a hetero-junction PV (HPV) cell the pure dephasing can indeed induce ENAQT. The situation of ENAQT in such a PV cell is quite different from that of a molecular junction placed in between leads in the sense that PV cell is continuously receiving photons from the solar radiation. Furthermore, in absence of dephasing vibration can also assist the electron transport through the junction.

It is worthwhile to point out that both vibration and dephasing are environmental effects on the HPV cell, the former being a localized environment and the latter characterizing an environment exhibiting a flat spectrum corresponding to the single dephasing rate. However, in the presence of both electron-vibration interactions and dephasing, a situation which to the best of our knowledge has not been investigated so far, the transport is actually hampered. Such a situation is quite realistic in view of the natural occurrence of vibration in molecular junc-

tions and the noise induced dephasing inherent to a system placed in finite temperature.

II. MODEL

We consider an organic hetero-junction photo-voltaic cell (HPV cell) which is essentially a junction of coupled donor and acceptor molecules placed in-between two (left L, and right R) metallic leads. The minimal model for such an HPV cell consists of two “effective” sites (the corresponding Hilbert space is denoted as \mathcal{H}_{sites}), the donor (D) and the acceptor (A)^{9,10}. Both the donor and the acceptor are represented by two state systems with energy levels $(\epsilon_{D1}, \epsilon_{D2})$ and $(\epsilon_{A1}, \epsilon_{A2})$ corresponding to the (HOMO, LUMO) levels of them respectively. The most important energy scales in the system are HOMO-LUMO gap, $\Delta E = (\epsilon_{D2} - \epsilon_{D1})$, and the donor-acceptor band gap, $\Delta\epsilon = \epsilon_{D2} - \epsilon_{A1}$, where the acceptor HOMO (ϵ_{A1}) does not take part in the operation of the cell⁹. The cell is placed under solar radiation which excites electrons from D-HOMO to D-LUMO (this process is termed as radiative transition). Moreover, the vibrational degrees of freedom, i.e., phonons of the donor molecule can cause non-radiative transitions between D-HOMO and D-LUMO.

Molecular Hamiltonian: The quantum mechanical Hamiltonian for the above model of the HPV cell is written as $H = H_e + H_{e-ph} + H_{ph}$. The electronic part of the total Hamiltonian is given by,

$$H_e = \sum_i \epsilon_i c_i^\dagger c_i - t(c_{D2}^\dagger c_{A2} + \text{h.c.}), \quad (1)$$

where $i = \{D_1, D_2, A\}$, c_i and c_i^\dagger are the electron annihilation and creation operators respectively, and t is the hopping amplitude between the D-LUMO and the A-LUMO.

Electron-phonon interaction Hamiltonian: The interaction between the electrons of the D-A complex and the phonons are originated from the vibrational degrees of freedom of the parent molecules of the donor and the acceptor. The corresponding electron-phonon (e-ph) interaction Hamiltonian is given by,

$$H_{e-ph} = \frac{\lambda_{e-ph}}{2} \left[(b^\dagger + b) c_{A2}^\dagger c_{D2} + \text{h.c.} \right], \quad (2)$$

where b (b^\dagger) annihilates (creates) phonons, λ_{e-ph} being e-ph coupling strength (a further simplification is obtained by taking the rotating wave approximation to this Hamiltonian). The transfer of electrons between the donor and the acceptor is therefore governed by two mechanisms, one being the electron hopping with strength ‘ t ’, and the other being the non-radiative (e-ph) mechanism described by the above Hamiltonian which transfers electrons from donor to acceptor by creating or annihilating phonons. The Hamiltonian for the phonon bath is

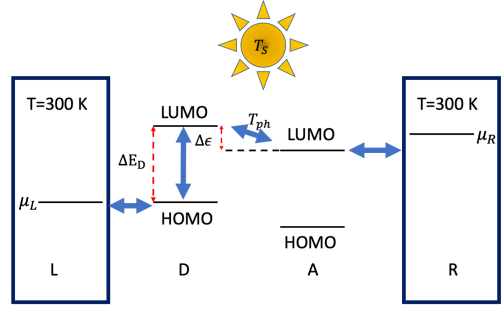


FIG. 1. A minimal model for the molecular photo-voltaic cell incorporating the possible heating effect. Transfer of electron between the donor LUMO and the acceptor LUMO is controlled by two mechanisms, viz., electron hopping mechanism (characterized by an electron temperature T_e) and electron-phonon interaction (characterized by temperature T_{ph} , as indicated in the figure). In our study we take $T_e = T_{ph} = 300$ K.

$H_{ph} = \omega_0 b^\dagger b$ with $\omega_0 = 0.1$ eV being the phonon energy, and the corresponding Hilbert space is denoted by \mathcal{H}_{ph} .

The dynamics of the above mentioned system, i.e., the HPV cell with Hamiltonian H is investigated within the Lindblad Master equation formalism, viz., $\dot{\rho} = -\frac{i}{\hbar}[H, \rho] + \sum_j (V_j \rho V_j^\dagger - \frac{1}{2}\{V_j^\dagger V_j, \rho\})$ where ρ is the density matrix in the Hilbert space, $\mathcal{H}_{sites} \otimes \mathcal{H}_{ph}$ of the combined electron phonon system. and V_j are a set of Lindblad operators which encode the effects of the coupling to the environment^{35–38}. We model the photon and the phonon bath corresponding to the radiative and non-radiative transitions between the D-HOMO and the D-LUMO by suitable Lindblad V -operators. Such a model replaces the explicit appearance of phonon and photon baths considered in Ref.¹⁰, but mimics the relevant radiative and non-radiative transitions. The radiative part of the V -operators are given by,

$$\begin{aligned} V_{D2 \rightarrow D1}^r &= \sqrt{\gamma_{pht}[n_B(\Delta E, T_s) + 1]} c_{D1}^\dagger c_{D2} \\ V_{D1 \rightarrow D2}^r &= \sqrt{\gamma_{pht} n_B(\Delta E, T_s)} c_{D2}^\dagger c_{D1}, \end{aligned} \quad (3)$$

where $n_B(\Delta E, T_s) = \frac{1}{\exp(\frac{\Delta E}{k_B T_s}) - 1}$ is the Bose-Einstein distribution with Solar temperature $T_s = 5700$ K and the superscript ‘ r ’ denotes the radiative part. γ_{pht} is the rate of excitation or de-excitation of photons. We can write a similar pair of Lindblad V -operators for the non-radiative (denoted by superscript ‘ nr ’) transition, viz.,

$$\begin{aligned} V_{D2 \rightarrow D1}^{nr} &= \sqrt{\gamma_{phn}[n_B(\Delta E, T_{ph}) + 1]} c_{D1}^\dagger c_{D2} \\ V_{D1 \rightarrow D2}^{nr} &= \sqrt{\gamma_{phn} n_B(\Delta E, T_{ph})} c_{D2}^\dagger c_{D1}, \end{aligned} \quad (4)$$

γ_{phn} being the rate of excitation or de-excitation of phonons and T_{ph} being the phonon temperature which

we consider to be 300 K. In *Supplementary material* we elaborate on and benchmark the above mentioned model of the photon and phonon baths against the model where the non-radiative (electron-phonon) and radiative (electron-photon interaction) processes between D-HOMO and D-LUMO explicitly appears in the Hamiltonian.

AN additional form of environmental influence is *dephasing*, which is implemented via (zeno-type) measurement of local density. We consider here dephasing on the donor-LUMO and acceptor-HOMO states, which correspond to the Lindblad operators $V_{D_2} = \sqrt{\Gamma} c_{D_2}^\dagger c_{D_2}$ and $V_A = \sqrt{\Gamma} c_A^\dagger c_A$, where Γ is the dephasing rate. These represent the process of fast repetitive measurement of occupation at D-LUMO and A-LUMO respectively at the same rate^{26–31}.

We compute the efficiency at maximum power η , which is an important measure of the operational efficiency of the HPV cell^{9,10,39}. This is defined as the ratio between the cell's maximal output power P_{out} , and the corresponding input power P_{in} supplied by the photons, viz., $\eta = \frac{P_{out}[max]}{P_{in}[max]}$ ^{39,40}. The maximal output power $P_{out}[max] = J_{out}(V_{max})V_{max}$, J_{out} being the output current and the corresponding input power $P_{in}[max] = J_S(V_{max})\Delta E$, where J_S is the light induced current between the D-HOMO and the D-LUMO. See *supplementary material* for the definitions of all the currents and powers.

III. RESULTS

A. ENAQT in absence of e-ph interaction

We start by investigating the effects of dephasing on the efficiency at maximum power η (henceforth the efficiency η) in absence of any e-ph interaction (2) whereby the system is described only by the Hamiltonian (1). In our calculation we set the orbital energies at $\epsilon_{D_1} = -0.1$ eV and $\epsilon_{D_2} = 1.4$ eV, the excitation rates $\gamma_{pht} = \gamma_{phn} = 10^{12} \text{ sec}^{-1}$, and the donor-acceptor electron hopping strength to be $t = 0.05$ eV.

In Fig. 2 the efficiency at maximum power η is plotted as a function of ϵ_A and dephasing rate Γ . We observe three distinct regime of dephasing rates along with the corresponding optimum values of ϵ_A : (i) at small dephasing rate $\Gamma \lesssim 10^{11} \hbar$ (in eV) the system is close to a quantum one with optimum $\epsilon_A = 1.53$ eV. In this regime the dynamics of the system is dominated by the electron hopping strength t .

(ii) When dephasing rate increases to a critical regime where Γ becomes comparable to ϵ_A , the donor-acceptor electron hopping mechanism combines with the dephasing to increase the efficiency of electron transfer. This regime corresponds to the ENAQT (enviornment assisted quantum transport) regime with the optimum $\epsilon_A = 2.15$ eV^{29,30}.

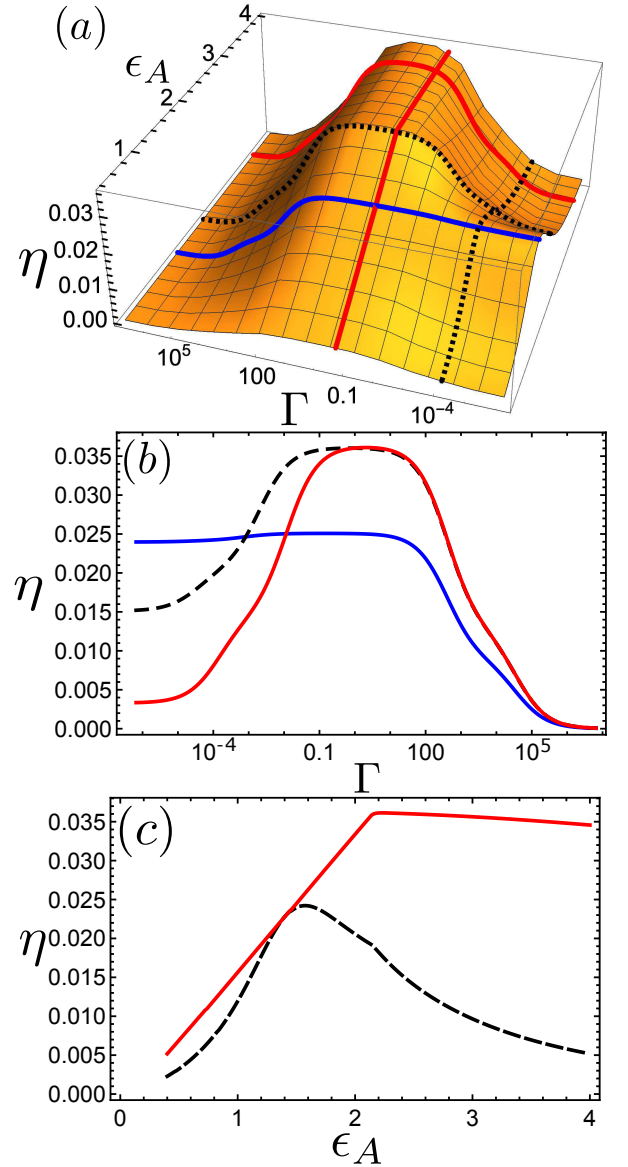


FIG. 2. (a) The density plot for the efficiency at maximum power η as a function of acceptor energy level ϵ_A (in eV) and dephasing rate Γ (in the units of eV). The color code represents the magnitude of η . (b) Plot of η as a function of Γ for three different acceptor level positions, viz., $\epsilon_A = 1.53$ eV (blue solid line), 2.15 eV (black solid line) and 3.5 eV (red solid line). These are indicated in (a) by vertical solid lines. (c) Plot of η as a function of ϵ_A for dephasing rates $\Gamma = 10^{11} \hbar$ eV (black dashed line) and $10^{15} \hbar$ eV (red solid line). These are indicated in (a) by horizontal dashed lines.

(iii) A third regime corresponding to $\Gamma \gtrsim (10^{20} \hbar)$ eV where the system become classical and all the electron transfers are reduced by the dephasing process. In this case the efficiency drops substantially (becoming roughly inversely proportional to the dephasing rate⁴¹). It is worthwhile to point out that the width of the ENAQT regime is controlled by the rate of injection of electrons at the D-LUMO level, which in our system is determined by

the resultant of radiative (γ_{ph}) and non-radiative (γ_{phn}) transfer rates⁴².

B. Efficiency at the maximum power in presence of e-ph interaction: phonon assisted transport

Having established the presence of ENAQT in our system, we now investigate the effect of e-ph interaction (corresponding to the Hamiltonian (2)) on the efficiency at maximum power η , but without exposing the system to environment (i.e., without taking into account the dephasing effect). In Fig. 3 the efficiency at maximum power η is plotted as a function of ϵ_A and λ_{e-ph} . From Fig. 3 it can be seen that for smaller values of $\lambda_{e-ph} \lesssim 0.01$ eV the efficiency η peaks at $\epsilon_A = 1.25$ eV. When λ_{e-ph} increases more than 0.01 eV, η develops a two peak structure with maximum of η for $\lambda_{e-ph} = 0.032$ eV.

Such a two peak structure of the efficiency at maximum power η as a function of the acceptor level ϵ_A can be understood by considering the dependence of the occupation on the A-LUMO positions. The electron occupations (n_{D-HOMO} , n_{D-LUMO} , and n_{A-LUMO}), and phonon occupation (see supplementary material for the definitions of the electron and phonon occupations) are plotted as functions of ϵ_A in Fig. 4 (a) and (b) respectively, for $t = 0.05$ eV and $\lambda_{e-ph} = 0.032$ eV. Careful observation of Fig. 4 (a) and (b) in comparison with the black solid curve corresponding to Fig. 3 reveals that peaks in η appear at those values of ϵ_A for which n_{A-LUMO} gets its peaks and both the n_{D-HOMO} and n_{D-LUMO} get its local dips.

This correspondence between peak positions of efficiency and populations indicates that at these positions of A-LUMO, transfer of electrons to A-LUMO is maximized, leading to an increased efficiency. These are the electrons which get excited from the D-HOMO due to solar radiation (duly counterbalanced by the non-radiative re-combinations), and at the above mentioned values of ϵ_A (corresponding to the two peaks in η) the rate of excitation becomes maximal leading to dips in n_{D-HOMO} . Subsequently, the excited electrons are transferred to A-LUMO via D-LUMO leading to almost feature-less n_{D-LUMO} near the two peaks of η . Furthermore, Fig. 4 (b) indicates that phonon occupation also gets its local peaks at the same values of ϵ_A . This feature leads us to infer that the transport here is phonon-assisted.

It is worthwhile to point out that n_{ph} exhibits a resonant dip at $\epsilon_A = \epsilon_{D_2}$ ($= 1.4$ eV) and correspondingly n_{D-LUMO} becomes more than n_{A-LUMO} (at $\epsilon_A = \epsilon_{D_2}$ they becoming equal). On the contrary, there exists another such crossing at $\epsilon_A = 0.9$ eV where n_{A-LUMO} becomes more than n_{D-LUMO} where the n_{ph} remains featureless because of the fact that at this position of the acceptor level no resonance condition (such as $\epsilon_A = \epsilon_{D_2}$) gets satisfied.

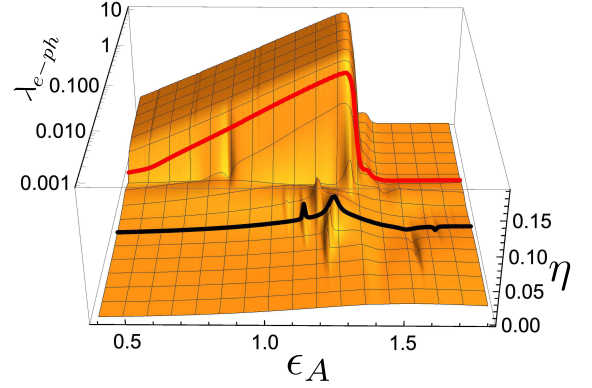


FIG. 3. Efficiency at maximum power η as a function of acceptor energy level ϵ_A (in eV) and e-ph coupling strength λ_{eph} (in eV). The color code represents the magnitude of η . (b) The black solid line and the red solid line correspond to the plot of η as a function of ϵ_A for $\lambda_{e-ph} = 0.032$ eV and 0.4 eV respectively.

To substantiate our interpretation of the phonon assisted transport, we argue that such a two peak structure (in efficiency vs acceptor energy) is a resonant effect inherited from the level crossing of the eigenvalues (real part) of the effective non-Hermitian Hamiltonian $H_{\text{eff}} = H - \frac{i}{2} \sum_j \gamma_j V_j^\dagger V_j$, where $\sqrt{\gamma_j}$'s are the rates associated to the Lindblad operators V_j 's. The real part of a few eigenvalues of H_{eff} are plotted in Fig. 5 as a function of acceptor level's energy ϵ_A , the imaginary part being the life-time of the system to remain in the corresponding eigenstate. Only eigenstates for which the eigenvalues are within the range of our interest, i.e., within the range of values of ϵ_A where η shows the two peak structure, are shown.

As seen from Fig. 5, the system exhibits several level crossings as the acceptor energy (hence acceptor position) is increased gradually to pass across the D-LUMO (ϵ_{D_2}) level. Comparing Figs. 4 (a) and (b) with Fig. 5 one can clearly see the $\epsilon_A = 1.14$ and 1.25 eVs level crossings, associated with the two peak structure of η .

In order to analyze the nature of transport near these resonances, in Fig. 6 the eigenvectors corresponding to the levels participating in the crossings are plotted as scatter plots; the index corresponding to the encircled dots represent the diagonal elements of the Hamiltonian H which in turn represent the most dominant system configuration contributing to the eigenstate. Considering the fact that the eigenstates can be written as $|\psi_n\rangle = \sum_{j=1}^N a_{n,j} |e_j\rangle$ where $N = 2^3 \times N_{ph}$ is the dimension of the Hilbert space for truncated Bosonic space containing N_{ph} number of phonons, and $|e_j\rangle$ are the unit vectors in the Hilbert space $\mathcal{H}_{\text{sites}} \otimes \mathcal{H}_{ph}$, such a configuration can be thought of as a semi-classical configuration of the system. This is in the sense that we are taking only a few a_j s and the corresponding $|e_j\rangle$ s as the system configuration.

At $\epsilon_A = 1.14$ eV for the level crossing from E_{18} to

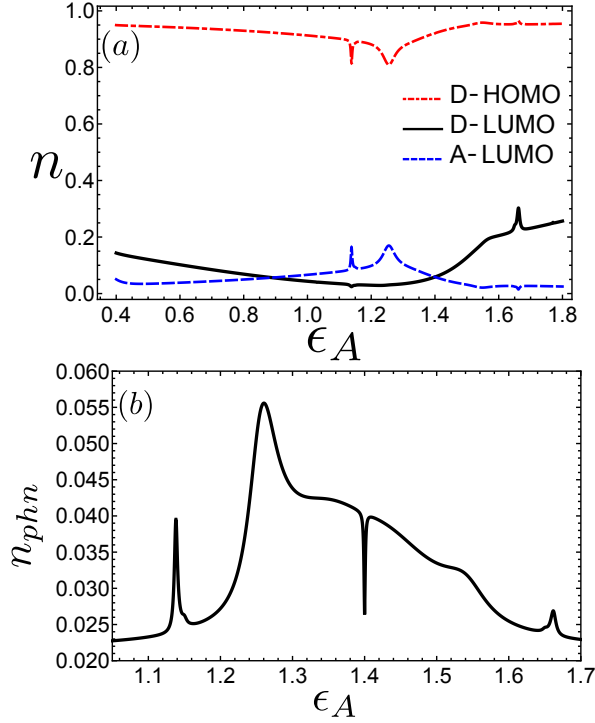


FIG. 4. (a) Occupation numbers corresponding to D-HOMO, D-LUMO, and A-LUMO and (b) plot of the phonon density as a function of ϵ_A for hopping strength $t = 0.05$ eV and e-ph coupling strength $\lambda_{e-ph} = 0.32$ eV. These correspond to the black solid line of Fig. 3.

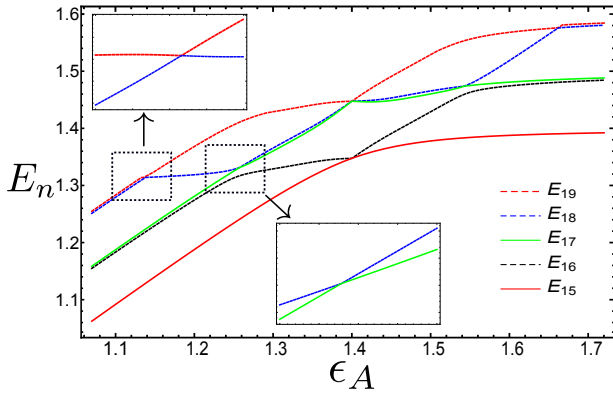


FIG. 5. Plot of the real part of the eigenvalues E_n of the n 'th eigenstate of the non-Hermitian Hamiltonian H_{eff} mentioned above. All the level crossing appearing in the plot occur at the values of ϵ_A for which n_{ph} of Fig. 4 (b) shows either a local peak or a local dip. At $\epsilon_A = 1.14$ eV the level crossing occurs between E_{18} and E_{19} , and at $\epsilon_A = 1.25$ eV the level crossing occurs between E_{17} and E_{18} and these are the crossing corresponding to the two local peaks in Fig. 3(b).

E_{19} the encircled dots represent a transition from the system configuration $\epsilon_{D_1} + \epsilon_A + 3\omega_0$ to $\epsilon_A + 2\omega_0$ indicating a transfer of one electron from donor to the right lead via the acceptor and a subsequent emission of one phonon of energy ω_0 . It is worthwhile to mention that within our model, the participation of the high energy phonons dominates the transport. At $\epsilon_A = 1.25$ eV for the level crossing from E_{17} to E_{18} the corresponding encircled dots represent a transition from $(\epsilon_{D_1} + \epsilon_A + 3\omega_0, \epsilon_{D_1} + \epsilon_{D_2} + 2\omega_0)$ to $(\epsilon_A + \omega_0, \epsilon_A)$ and subsequent emission of two phonons of energy ω_0 . Therefore at the first peak in η the transport involves a one phonon process and while at the second peak it involves two phonon processes. Furthermore, at both the values of ϵ_A , phonon emissions are involved in the electrons transfer processes and such emissions indeed increase the phonon occupation as seen from corresponding peaks in n_{phn} in Fig. 4 (b).

Going back to Fig. 3; for large enough e-ph coupling strength corresponding to $\lambda_{eph} \gtrsim 0.3$ eV (henceforth considered as strong e-ph coupling regime), the maximum of the efficiency η is found at the optimum $\epsilon_A = 1.32$ eV. The maximum value of η is around five fold more than what can be obtained in an electron-only mechanism of charge transport in HPV cells even in the ENAQT regime. This is due to the (rather well-known) fact that e-ph coupling opens up more channels for electron to get transferred from D-LUMO to A-LUMO, and in the strong e-ph coupling regimes these channels dominantly participate in transferring electrons leading to the enhanced efficiency. Furthermore, the optimum value of ϵ_A , mentioned above, is weakly dependent of the e-ph coupling strength in the strong e-ph coupling regime. The intuitive way to understand why the maximum of η occurs at this particular value of ϵ_A is as follows. From the red solid line corresponding to $\lambda_{e-ph} = 0.4$ eV in Fig. 3 (b) we see that η keeps increasing as the absolute position of the acceptor level approaches to the absolute position of the D-LUMO (in other words $\Delta\epsilon$ decreases). This happens because, with the A-LUMO approaching the D-LUMO the overlap between the wave-functions of these two levels increases, and consequently the phonon mediated transfer of electrons from D-LUMO to A-LUMO also increases. This results in an increased efficiency. As long as $\epsilon_A < \epsilon_{D_2}$ the electrons from D-LUMO gets transferred to A-LUMO by creating a phonon mode. When the situation $\epsilon_A > \epsilon_{D_2}$ appears the phonon mediated mechanism ceases to occur and the efficiency drops.

C. Environment hampered transport in the presence of e-ph interaction

We now expose our combined electron phonon system to the environment via applying dephasing on both D-LUMO and A-LUMO at the same rate. We consider the e-ph coupling strength to be $\lambda_{e-ph} = 0.4$ eV, a case in which the efficiency at maximum power η exhibits a

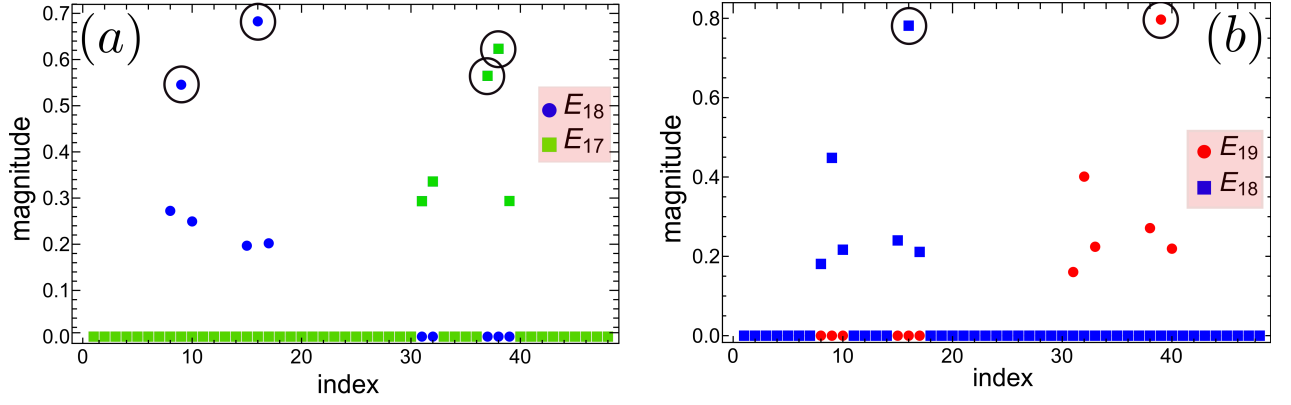


FIG. 6. Scatter plot for the eigenvectors corresponding to the eigenvalues which cross each other (a) at $\epsilon_A = 1.25$ eV, and (b) at $\epsilon_A = 1.14$ eV. The encircled ones represent the dominant system configuration contributing to the eigen-state.

maximum at $\epsilon_A = 1.32$ eV, as can be seen from Fig. 3 (b).

In Fig. 7, η is plotted as a function of the acceptor energy ϵ_A and the dephasing strength Γ . For $\epsilon_A = 1.32$ eV (for which the transport is dominated by the e-ph interaction) we can clearly see an environment hampered quantum transport. This can be identified from the local dip in the η in the regime of the dephasing rate which is otherwise the regime of ENAQT when the mechanism of transport was electron hopping only. The red dashed curve corresponding to Fig. 7 provides η as a function of dephasing rate Γ for $\epsilon_A = 1.45$ eV where the transport is due to electron hopping mechanism as the e-ph mechanism ceases to exist. A subsequent peak in the higher dephasing rate can be seen however, at this peak η remains less than its values corresponding to the low dephasing regime corresponding to $\Gamma \lesssim 10^{12}\hbar$. This points to the fact that the ENAQT is never achieved when both the e-ph mechanism of transport and the dephasing are present together.

This environment hampered transport can be understood from the behavior of both the electron and the phonon occupations as a function of Γ . In Fig. 8, the occupation of electrons in D-HOMO, D-LUMO, and A-LUMO and phonon occupation n_{phn} at maximum power are plotted as a function of dephasing rate Γ . First of all, comparing Figs. 7 and 8 it can be seen that the behaviour of η as a function of Γ is same as that of the n_{A-LUMO} , indicating that η is directly proportional to the A-LUMO occupation at maximum power.

Moreover, three distinct regimes of transport are observed: (i) At small dephasing rate $\Gamma \lesssim 10^{12}\hbar$ electron density in A-LUMO is more than D-LUMO occupation and phonon occupation, although the dephasing rate Γ is the same for both D-LUMO and A-LUMO. Therefore, more electrons are available at A-LUMO to be absorbed in the right lead which results in an increased η . In this regime electrons are transferred from D-HOMO to A-LUMO via D-LUMO by creating phonon modes, virtually spending no time in the D-LUMO.

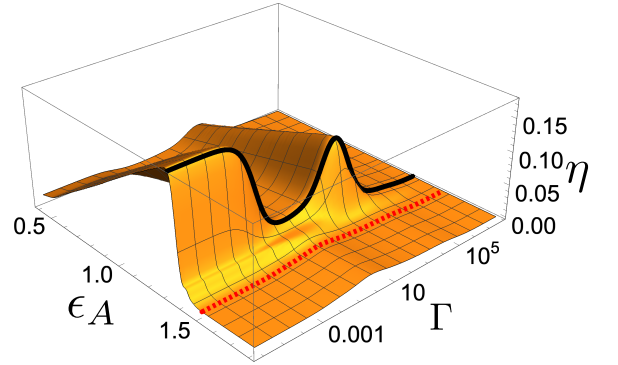


FIG. 7. The plot of efficiency at maximum power η as a function of acceptor energy level ϵ_A (in eV) and dephasing rate Γ (in eV) for $\lambda_{e-ph} = 0.4$ eV. The black solid line and the red dashed line correspond to plot of η as a function of Γ for $\epsilon_A = 1.32$ eV and 1.45 eV respectively. The local minimum appearing in the black solid line is at $\Gamma = 0.51$ eV.

(ii) For $\Gamma \gtrsim 10^{12}\hbar$ the phonon occupation starts increasing and the A-LUMO occupation starts decreasing which indicates with the increased dephasing the phonon bath gets populated by de-populating the A-LUMO. Dephasing, being a process mimicking the physical process of repeated measurements, tends to populate equally both the D-LUMO and A-LUMO by de-localizing electrons in the respective levels. In this process it essentially blocks most of those transport channels, which were otherwise available in the low dephasing regime due to electron phonon coupling, thereby reducing the phonon assisted transport of electrons from donor to acceptor resulting in a reduced n_{A-LUMO} . Therefore, the transfer of electrons from D-LUMO to A-LUMO is hampered by dephasing (therefore, by the environment). In this situation all the absorbed solar energy gets utilized to increase the n_{phn} , as can be seen from Fig. 8.

Furthermore, in this regime corresponding to $10^{12}\hbar < \Gamma < 10^{18}\hbar$, the dephasing also hampers the effective in-

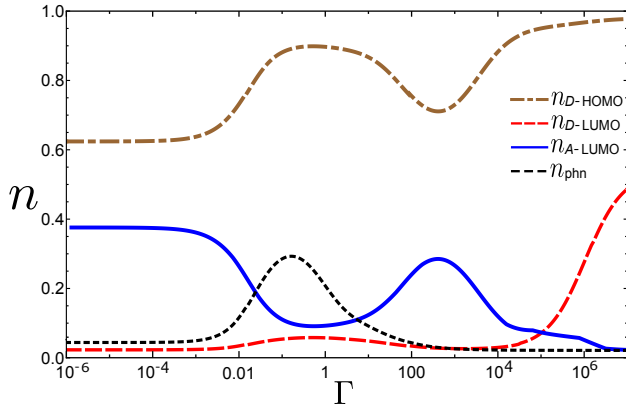


FIG. 8. The plot of the electron occupations, n_{D-HOMO} (brown dot-dashed line), n_{D-LUMO} (red long-dashed line), and n_{A-LUMO} (blue solid line), and phonon occupation n_{phn} (black short-dashed line) at maximum power as functions of dephasing rate Γ (in eV) for bias voltages for which the output power is maximum.

jection of electrons in the D-LUMO level, as can be seen from the increased electron occupation in D-HOMO in this regime. When the dephasing rate exceed that of the transfer of electrons from D-HOMO to D-LUMO, it traps electrons in D-LUMO at a rate faster than the rate of excitation of electrons to D-LUMO leading to increased D-HOMO occupation. At resonant dephasing rate, corresponding to $\Gamma_R = 0.51\text{eV}$, electron density in A-LUMO is minimized locally in order to make occupation in A-LUMO and D-LUMO nearly equal (in this situation dephasing tends to populate both D-LUMO and A-LUMO equally²⁹). However, this is achieved in a manner that first the dephasing starts suppressing the e-ph transport channels which is maximized at $\Gamma = 0.17\text{ eV}$, and subsequently the n_{A-LUMO} gets suppressed.

In order to understand the resonant dephasing we have evaluated η and n_{phn} as a function of Γ for a few e-ph coupling strength λ_{e-ph} . These are plotted in *supplementary material*. It is found that the value of the resonant dephasing Γ_R increases with the increasing λ_{e-ph} . Physically, this indicates that with increasing e-ph coupling strength one needs a faster dephasing rate to suppress the available e-ph transport channels.

(iii) For $\Gamma \gtrsim 10^{18}\hbar$ the A-LUMO gets repopulated while the phonon modes get de-populated resulting in an increased η . This is a situation corresponding to an off-resonant dephasing where all the transport channels provided by the e-ph coupling get open again.

(iv) Lastly, at even higher dephasing rate $\Gamma \gtrsim 10^{21}\hbar$ all the electrons are being populated at D-LUMO and D-HOMO, as can be seen from brown dot-dashed and red dashed curves corresponding to Fig. 8. This leads to a vanishing electron transport, thereby vanishing η .

IV. SUMMARY AND CONCLUSIONS

In this manuscript, we have presented a generic model for the efficiency at maximum power of a molecular photo-cell subjected to the influence of an environment. We consider two general forms for the molecular environment, namely (a) a localized molecular vibration coupled to the electron orbitals, and (b) local dephasing (e.g. by a continuous Zeno-like measurement of the electron orbital density), corresponding to a broad continuous spectrum of soft vibrations. We study the effect of each of these forms separately, and then the combined effect.

The interplay between these environments and the electronic system gives rise to a rich set of effects, fingerprinted in the efficiency of the molecular photo-cell. We evaluate the efficiency for a wide range of parameters, and provide detailed insight into the origins of the specific features of the efficiency.

Our main findings are as follows:

- In the presence of dephasing, the molecular photo-cell exhibits the so-called "environment assisted quantum transport", showing a non-monotonic dependence of the efficiency on dephasing rate. The optimal dephasing rate seems to be only weakly dependent on the position of the acceptor LUMO energy level (Fig. 2).
- In the absence of dephasing, the effect of a localized vibration is characterized by two regimes (Fig. 3). For weak electron-phonon coupling the system exhibits resonant behavior, the resonances correspond to coupled electron-phonon states, i.e. phonon-assisted transport. For strong electron-photon coupling, the system exhibits a line-shape similar to the classical system^{9,10}, prompted by the high phonon occupation.
- The combination of strong electron-phonon couplings and dephasing leads to environment-hampered transport, where there is a minimum in the efficiency for some specific dephasing rate (Fig. 7).

Our results suggest that the co-action of the classical environment and the quantum mechanical electronic system brings in distinct parameter regimes of environment assisted and environment hampered transport which, from the design perspective, implies a need for careful tuning of parameters of the real systems. Recent advances in the experimental ability to measure the photovoltaic conversion efficiency in single molecule junctions and PV cells make our theoretical findings experimentally verifiable^{1,8,43}. It would be interesting to study these competing environmental effects in natural photosynthetic systems owing to their conceptual similarity with the HPV cells. The resonant dephasing rate corresponding to the environment hampered transport is expected to be in commensurate with the energy scales of photo-synthetic systems.

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